

# LM185QML Adjustable Micropower Voltage References

Check for Samples: LM185QML

## **FEATURES**

- Adjustable from 1.24V to 5.30V
- Operating Current of 10µA to 20mA
- 1Ω Dynamic Impedance
- Low Temperature Coefficient

## DESCRIPTION

The LM185 are micropower 3-terminal adjustable band-gap voltage reference diodes. Operating from 1.24 to 5.3V and over a 10µA to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185 band-gap reference uses only transistors and resistors, low noise and good long-term stability result.

Careful design of the LM185 has made the device tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part.

## **Connection Diagrams**



Figure 1. PFM Metal Can Package (Bottom View)

See Package Number NDV0003H

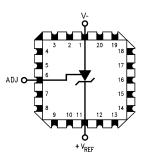
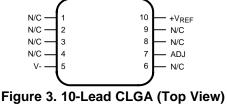


Figure 2. 20-Leadless Chip Carrier (Top View) See Package Number NAJ0020A



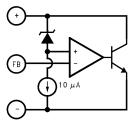
See Package Number NAC0010A



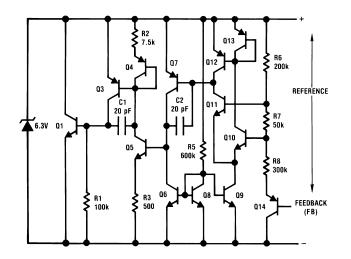
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## **Block Diagram**



## **Schematic Diagram**





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



Package Weight (Typical)

ESD Tolerance<sup>(2)</sup>

### .... Absolute

Absolute Maximum Ra	tings <sup>(1)</sup>					
Reverse Current	30mA					
Forward Current			10mA			
Operating Temperature Range			–55°C ≤ T <sub>A</sub> ≤ 125°C			
Storage Temperature			−55°C ≤ T <sub>A</sub> ≤ 150°C			
Maximum Junction Temperature	e T <sub>Jmax</sub>		150°C			
Lead Temperature (soldering, 10	ead Temperature (soldering, 10 seconds)					
Thermal Resistance	$\theta_{JA}$	LCCC Package (Still Air)	100°C/W			
		LCCC Package (500LF/Min Air flow)	73°C/W			
		Metal Can Package (Still Air)	300°C/W			
		Metal Can Package (500LF/Min Air flow)	139°C/W			
		CLGA Package (Still Air)	194°C/W			
		CLGA Package (500LF/Min Air flow)	128°C/W			

LCCC Package

**CLGA** Package

LCCC Package

**CLGA** Package

Metal Can Package

Metal Can Package

(1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is intended to be functional. For guaranteed specifications and test conditions, see the Electrical Characteristics.

Human body model, 1.5 k $\Omega$  in series with 100 pF. (2)

 $\theta_{\text{JC}}$ 

### **Table 1. Quality Conformance Inspection** Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

25°C/W

57°C/W

23°C/W

TBD

TBD

210mg

500V

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STRUMENTS

Texas

## LM185B Electrical Characteristics DC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups	
V <sub>Ref</sub>	Reference Voltage	I <sub>R</sub> = 100μA		1.228	1.252	V	1	
				1.215	1.255	V	2, 3	
		$I_R = 9\mu A$		1.228	1.252	V	1	
		I <sub>R</sub> = 10μΑ		1.215	1.255	V	2, 3	
		I <sub>R</sub> = 1mA		1.228	1.252	V	1	
				1.215	1.255	V	2, 3	
		I <sub>R</sub> = 20mA		1.228	1.252	V	1	
				1.215	1.255	V	2, 3	
		$V_{R} = 5.3V, I_{R} = 100\mu A$		1.228	1.252	V	1	
				1.215	1.255	V	2, 3	
		$V_{R} = 5.3V, I_{R} = 45\mu A$		1.288	1.252	V	1	
		$V_{R} = 5.3V, I_{R} = 50\mu A$		1.215	1.255	V	2, 3	
		V <sub>R</sub> = 5.3V, I <sub>R</sub> = 1.0mA		1.288	1.252	V	1	
				1.215	1.255	V	2, 3	
		V <sub>R</sub> = 5.3V, I <sub>R</sub> = 20mA		1.288	1.252	V	1	
			1.215	1.255	V	2, 3		
$\Delta V_{Ref} / \Delta I_R$	Reference Voltage	9µA ≤ I <sub>R</sub> ≤ 1mA			1.0	mV	1	
	Change with Current	10µA ≤ I <sub>R</sub> ≤ 1mA			1.5	mV	2, 3	
		$1mA \le I_R \le 20mA$			10	mV	1	
					20	mV	2, 3	
		$V_R = 5.3V, 45\mu A \le I_R \le 1mA$			1.0	mV	1	
		$V_R = 5.3V, 50\mu A \le I_R \le 1mA$			1.5	mV	2, 3	
		$V_R = 5.3V$ , $1mA \le I_R \le 20mA$			10	mV	1	
					20	mV	2, 3	
ΔV <sub>Ref</sub> /	Reference Voltage	V <sub>R</sub> = 5.3V, I <sub>R</sub> = 100µA			3.0	mV	1	
ΔV <sub>O</sub>	Change with Output Voltage				6.0	mV	2, 3	
F	Feedback Current	$I_R = 9\mu A$			20	nA	1	
		I <sub>R</sub> = 10μΑ			25	nA	2, 3	
		I <sub>R</sub> = 20mA			20	nA	1	
					25	nA	2, 3	
		V <sub>R</sub> = 5.3V, I <sub>R</sub> = 45µA			20	nA	1	
		$V_{R} = 5.3V, I_{R} = 50\mu A$			25	nA	2, 3	
		V <sub>R</sub> = 5.3V, I <sub>R</sub> = 20mA			20	nA	1	
					25	nA	2, 3	
l <sub>c</sub>	Minimum Operating	$V_{R} = V_{Ref}$	See <sup>(1)</sup>		9.0	μA	1	
	Current		See <sup>(1)</sup>		10	μA	2, 3	
		V <sub>R</sub> = 5.3V	See <sup>(1)</sup>		45	μA	1	
			See <sup>(1)</sup>		50	μA	2, 3	

(1) Functional test.



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## LM185BY Electrical Characteristics DC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
V <sub>Ref</sub> Re	Reference Voltage	I <sub>R</sub> = 100μA		1.228	1.252	V	1
				1.215	1.255	V	2, 3
		$I_R = 9\mu A$		1.228	1.252	V	1
		$I_R = 10 \mu A$		1.215	1.255	V	2, 3
		I <sub>R</sub> = 1mA		1.228	1.252	V	1
				1.215	1.255	V	2, 3
		$I_R = 20 \text{mA}$		1.228	1.252	V	1
				1.215	1.255	V	2, 3
		$V_{R} = 5.3V, I_{R} = 100\mu A$		1.228	1.252	V	1
				1.215	1.255	V	2, 3
		$V_{R} = 5.3V, I_{R} = 45\mu A$		1.288	1.252	V	1
		$V_{R} = 5.3V, I_{R} = 50\mu A$		1.215	1.255	V	2, 3
		$V_R = 5.3V, I_R = 1.0mA$		1.288	1.252	V	1
				1.215	1.255	V	2, 3
		$V_{R} = 5.3V, I_{R} = 20mA$		1.288	1.252	V	1
				1.215	1.255	V	2, 3
ΔV <sub>Ref</sub> /ΔI <sub>R</sub> Reference Voltage Change with Current		$9\mu A \le I_R \le 1mA$			1.0	mV	1
	$10\mu A \le I_R \le 1mA$			1.5	mV	2, 3	
		$1mA \le I_R \le 20mA$			10	mV	1
					20	mV	2, 3
		$V_R = 5.3V, 45\mu A \le I_R \le 1mA$			1.0	mV	1
		$V_R = 5.3V, 50\mu A \le I_R \le 1mA$			1.5	mV	2, 3
		$V_R = 5.3V$ , 1mA $\leq I_R \leq 20$ mA			10	mV	1
					20	mV	2, 3
∆V <sub>Ref</sub> /	Reference Voltage	$V_R = 5.3V, I_R = 100\mu A$			3.0	mV	1
ΔV <sub>O</sub>	Change with Output Voltage				6.0	m∨	2, 3
I <sub>F</sub> Feedl	Feedback Current	I <sub>R</sub> = 9μA			20	nA	1
		I <sub>R</sub> = 10μA			25	nA	2, 3
		$I_R = 20 \text{mA}$			20	nA	1
					25	nA	2, 3
		$V_{R} = 5.3V, I_{R} = 45\mu A$			20	nA	1
		$V_{R} = 5.3V, I_{R} = 50\mu A$			25	nA	2, 3
		$V_{R} = 5.3V, I_{R} = 20mA$			20	nA	1
					25	nA	2, 3
С	Minimum Operating Current	$V_{R} = V_{Ref}$	See <sup>(1)</sup>		9.0	μA	1
	Guileni		See <sup>(1)</sup>		10	μA	2, 3
		V <sub>R</sub> = 5.3V	See <sup>(1)</sup>		45	μA	1
			See <sup>(1)</sup>		50	μA	2, 3
Т <sub>С</sub>	Temperature Coefficient		See <sup>(2)</sup>		50	PPM/°C	1, 2, 3

(1) Functional test.

(2) The average temperature coefficient is defined as the maximum deviation of reference voltage, at all measured temperatures between the operating T<sub>Min</sub> & T<sub>Max</sub>, divided by (T<sub>Max</sub> - T<sub>Min</sub>). The measured temperatures (T<sub>Measured</sub>) are -55°C, 25°C, & 125°C or ΔV<sub>Ref</sub> / (T<sub>Max</sub> - T<sub>Min</sub>)



 $I_R = 100 \ \mu A$ 

Vout = Vref

= 5.3V

50 75 100 125

Моит

25

Figure 5.

– 5<sup>5</sup>°C

55°C

100

TA=

Figure 7.

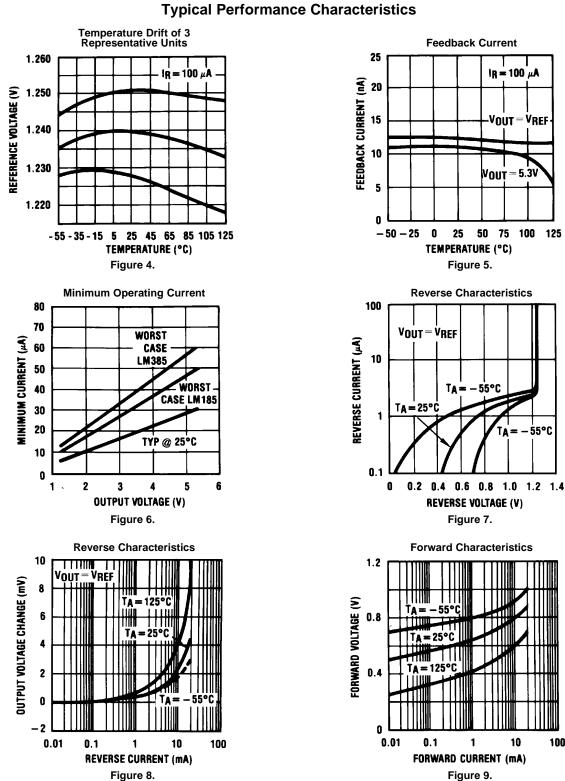
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Figure 9.

11

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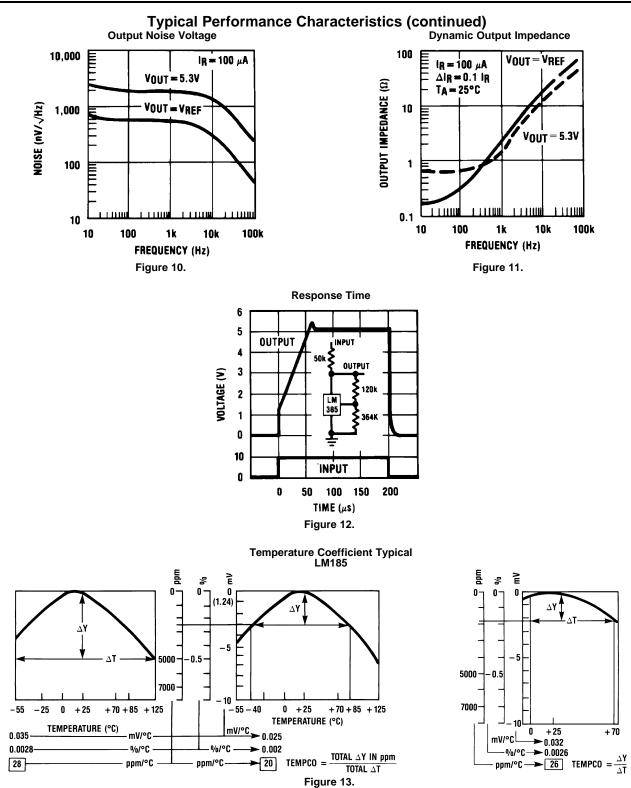
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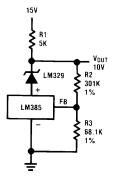


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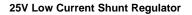


## **TYPICAL APPLICATIONS**





### Figure 14.



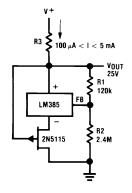
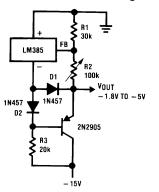
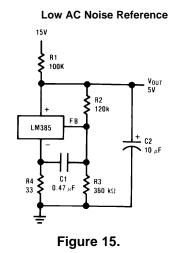


Figure 16.

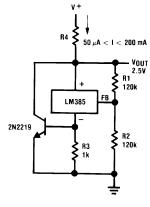
Series-Shunt 20 mA Regulator















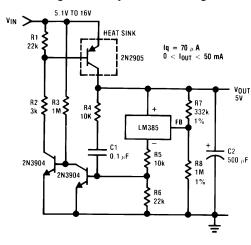
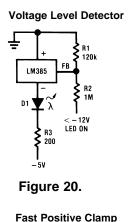


Figure 19.



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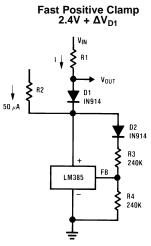
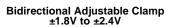


Figure 22.



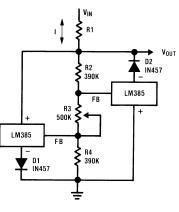


Figure 24.

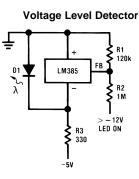


Figure 21.

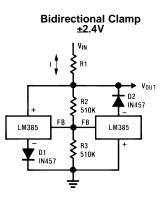
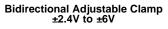


Figure 23.



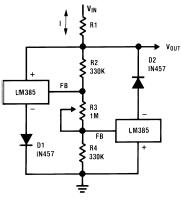


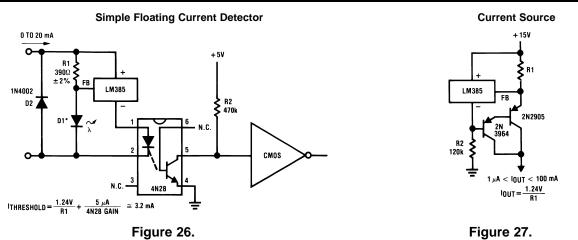
Figure 25.

# LM185QML

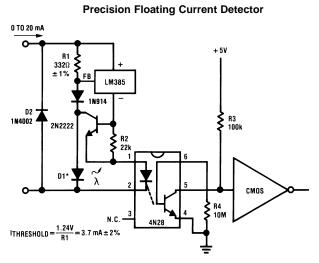


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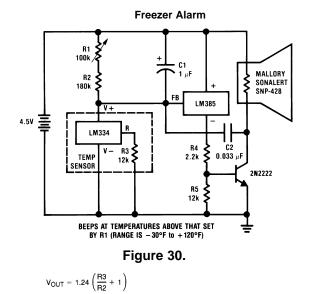
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\*D1 can be any LED,  $V_F$ =1.5V to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if  $I_{THRESHOLD}$  falls below the threshold current, except with I=O.







Centigrade Thermometer, 10mV/°C

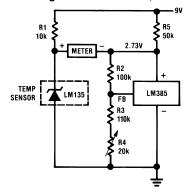
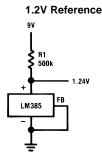


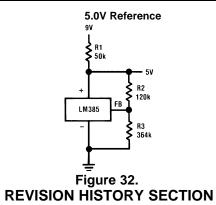
Figure 29.







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Released	Revision	Section	Originator	Changes
11/08/05	A	New Release, Corporate format	L. Lytle	2 MDS data sheets converted into one Corp. data sheet format. MNLM185B-X Rev 0B0 and MNLM185BY-X Rev 0B0 will be archived.
04/06/06	В	Ordering Information Table, WG Connection Diagram, Absolute Maximum Ratings Section, Physical Dimensions Section	R. Malone	Added NSID, Connection Diagram, Physical Dimension Dwg, Thermal Resistance and Package Weight for NAC package. Revision A will be Archived.
06/12/08	С	LM185B and LM185BY Electrical Section	Larry McGee	Correct IC test, $V_R = V_{REF}$ condition, subgroup 1, 2, 3 moved limits to the maximum column. Revision B will be Archived.

## PACKAGING INFORMATION

Orderable Device		Package Type			Package Qty	Eco Plan	Lead/Ball Finish	•	Op Temp (°C)		Samples
	(1)		Drawing			(2)		(3)		(4)	
5962-9091402QYA	ACTIVE	CLGA	NAC	10	54	TBD	Call TI	Call TI		LM185BWG /883 Q 5962-90914 02QYA ACO 02QYA >T	Samples
LM185BWG/883	ACTIVE	CLGA	NAC	10	54	TBD	Call TI	Call TI		LM185BWG /883 Q 5962-90914 02QYA ACO 02QYA >T	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package. or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp, -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

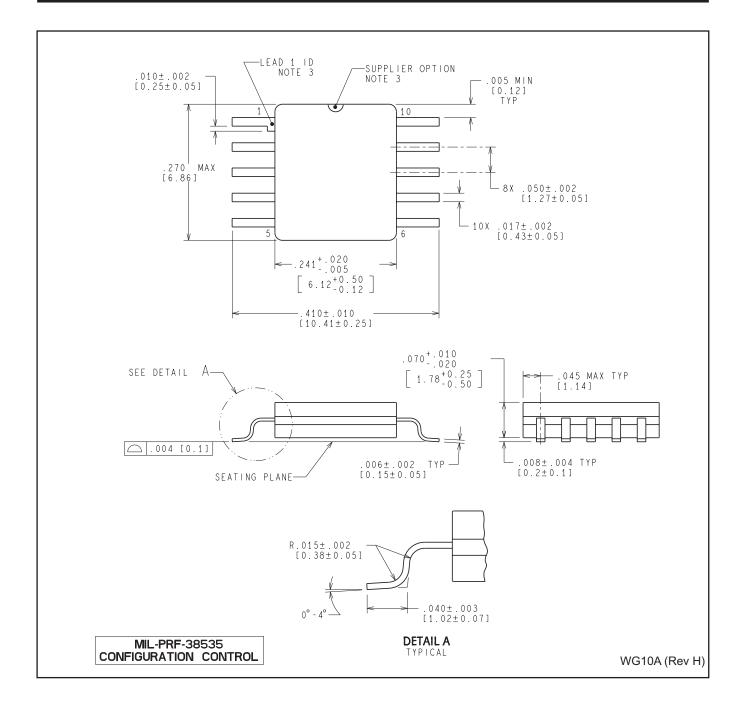
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Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
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